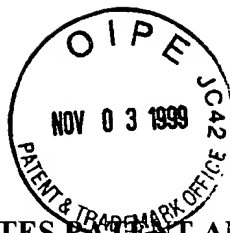


S/N 08/903,486



PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Leonard Forbes et al.

Examiner: W. Mintel

Serial No.: 08/903,486

Group Art Unit: 2811

Filed: July 29, 1997

Docket: 303.326US1

Title: SILICON CARBIDE GATE TRANSISTOR

PRELIMINARY AMENDMENT

Box CPA
Assistant Commissioner for Patents
Washington, D.C. 20231

In response to the Final Office Action mailed September 2, 1999, please amend the application as follows:

IN THE CLAIMS

Please cancel claims ~~16-21~~ and amend the claims as follows:

35. (Amended) The semiconductor memory device of claim 31 wherein each [an] insulating layer comprises silicon oxide

REMARKS

In response to the Final Office Action mailed September 2, 1999, the applicant requests reconsideration of the above-identified application in view of the following remarks. Claims 1-15 and 22-36 are pending in the application, and are rejected. Claims 16-21 have been cancelled. Claim 35 has been amended according to the suggestion of the Examiner. None of the pending claims have been amended in response to the rejections under 35 U.S.C. §103.

Information Disclosure Statement

The applicant filed a Supplemental Information Disclosure Statement on August 30, 1999. The applicant respectfully requests that this Information Disclosure Statement be entered and the documents listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to the provisions of MPEP 609, Applicants further request that a copy of the 1449 forms, initialed by the Examiner to indicate that all listed citations have been considered, be returned with the next official communication.

##4
Amended
J. Mintel
11/9/99

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